

# SCHOTTKY DIODE MODULE(NON-ISOLATED TYPE)

## BKR400ABZ50

Power Schottky Diode Module **BKR400ABZ50** is designed for various rectifier circuits.

**BKR400ABZ50** is suitable for high power application requiring low loss.

- Low  $V_{FM}$  0.57V ( $I_F=400A$ )

- $I_{F(AV)}=200A$  (each device)

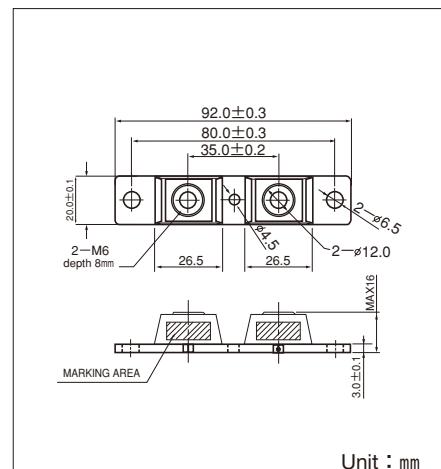
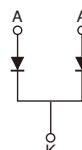
- $V_{RRM}=50V$

- High Surge Capability

(Applications)

Switching Power Supply, Power Supply for Metal Surface Treatment

Power Supply for Telecommunication



### ■ Maximum Ratings

( $T_j=25^\circ C$  unless otherwise specified)

Symbol	Item	Ratings		Unit
		<b>BKR400ABZ50</b>		
$V_{RRM}$	Repetitive peak reverse Voltage	50		V

Symbol	Item		Condition	Ratings	Unit
$I_{F(AV)}$	Forward Current	Per module	D.C. $T_c=127^\circ C$	400	A
		Per leg		200	
$I_{FMS}$	Surge Forward Current	$\frac{1}{2}$ cycle, 60Hz, Peak value. non-repetitive		7600	A
		$\frac{1}{2}$ cycle, 50Hz, Peak value. non-repetitive		6920	
$I^2t$	$I^2t$ (for fusing)		Value for one cycle of surge current	240000	A <sup>2</sup> s
$E_{AS}$	Single Pulse Avalanche Energy (Per Leg)		$I_{AS}=60A$ , $L=160\mu H$	320	mJ
$T_j$	Operating Junction Temperature			-40 to +150	°C
$T_{stg}$	Storage Temperature			-40 to +125	°C
	Mounting Torque	Mounting (M6)	Recommended value 25-40	48	kgf·cm
			Recommended value 2.5-3.9	4.7	N·m
		Mounting (M4)	Recommended value 10-14	15	kgf·cm
			Recommended value 1.0-1.4	1.5	N·m
		Terminal (M6)	Recommended value 25-40	48	kgf·cm
			Recommended value 2.5-3.9	4.7	N·m
	Mass		Typical value	78	g

### ■ Electrical Characteristics

Symbol	Item		Condition	Ratings	Unit	
$I_{RRM}$	Repetitive Peak Reverse Current	$T_j=125^\circ C$ , $V_R=50V$ , Pulse Width < 300 μs, Duty < 2%		2000	mA	
$V_{FM}$		$I_F=200A$ Inst. measurement		0.57	V	
		$I_F=400A$ Inst. measurement		0.73		
		$I_F=200A$ , $T_j=125^\circ C$ Inst. measurement		0.52		
		$I_F=400A$ , $T_j=125^\circ C$ Inst. measurement		0.68		
$R_{th(j-c)}$	Thermal Resistance (Per leg)	Junction to case		0.20	°C/W	

